





Wide Band GaAs MMIC Amplifier 2-8 GHz

Features

- High Gain: 17 dB
- Gain Flatness: ±0.5 dB
- Single Supply: +10 V
- No External Components Required
- DC Decoupled RF Input and Output
- Small, Low Cost 8-Lead Ceramic Package

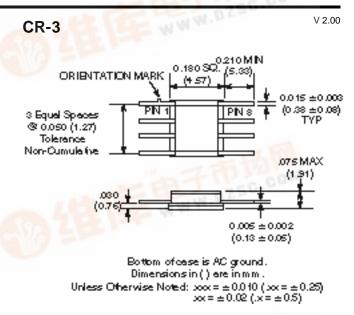
Description

.dzsc.com

M/A-COM's MAAM28000-A1 is a wide band, MMIC amplifier housed in a small 8-lead ceramic package. It includes two distributed gain stages to obtain flat gain and a good, 50-ohm, input and output impedance match over a very wide bandwidth. The MAAM28000-A1 operates from a single +10 V supply. It is fully monolithic, requires no external components, and is provided in a low-cost, user-friendly, microwave package.

The MAAM28000-A1 performs well as a generic IF, driver or buffer amplifier where high gain, excellent linearity and low power consumption are important. Because of its wide bandwidth, the MAAM28000-A1 can be used in numerous commercial and government system applications, such as satellite communications, RLL, EW and radar.

The MAAM28000-A1 is manufactured in-house using a reliable, 0.5-micron, GaAs MESFET process. This product is 100% RF tested to ensure compliance to performance specifications.



Ordering Information

Part Number	Package
MAAM28000-A1	8-Lead Ceramic
MAAM28000-A1	G Gull Wing



Electrical Specifications Test Conditions: T_A = +25°C, Z_O = 50 Ω , V_{DD} = +10 V, P_{IN} = -30 dBm

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Gain	-1. Fri 61/0	dB	14	17	
Noise Figure	2 - 4 GHz	dB		6.5	8.0
	4 - 6 GHz	dB		5.5	6.5
	6 - 8 GHz	dB		4.5	6.0
Gain Flatness		dB		± 0.5	
Input VSWR				1.6:1	
Output VSWR				1.5:1	
Output 1 dB Compression		dBm		+14	
Input IP ₃		dBm		+7	
Reverse Isolation		dB		35	
Bias Current		mA		70	100

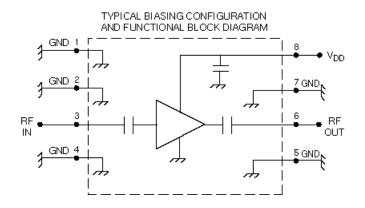
MAAM28000-A1

Absolute Maximum Ratings¹

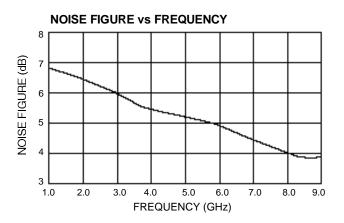
Parameter	Absolute Maximum		
V _{DD}	+14 volts		
Input Power	+20 dBm		
Current	150 mA		
Channel Temperature	+150°C		
Operating Temperature ²	-55°C to +100°C		
Storage Temperature	-65°C to +150°C		

Operation of this device outside these limits may cause permanent damage.
Typical thermal resistance (θjc) = +45°C/W

Schematic



GAIN vs FREQUENCY 20.0 18.0 (BP) 16.0 NIV (BVII) 14.0 12.0 10.0 9.0 3.0 7.0 1.0 5.0 FREQUENCY (GHz)



VSWR vs FREQUENCY 3.0 2.5 Output VSWR 2.0 Input 1.5 1.0 ∟ 1.0 3.0 5.0 7.0 9.0 FREQUENCY (GHz)

Typical Performance @ +25°C